

Product Information Brochure



Shadow Mask Aligner

Idonus Sarl Rouges-Terres 61 2068 Hauterive / NE Switzerland Phone : +41 32 724 44 40 Fax : +41 32 724 44 42 Email : info@idonus.com Web : www.idonus.com

General Information

Thin film deposition through a shadow mask is a powerful process for PVD layer structuring. It allows to replace one photolithographic and one etching step by precise masking of the substrate during deposition. A basic problem of the process is the alignment and temporary fixation of the shadow mask and the wafer.

Idonus provides a system for accurate and reproducible alignment of a shadow mask and a wafer with an integrated vibration-resistant clamping chuck. An alignment tolerance of 6 μ m was demonstrated with the help of a microscope. The chuck can directly be inserted in the vacuum chamber for PVD. After deposition the chuck is opened and the wafer and the mask are separated without damaging the wafer. The shadow mask can be reused.

Deposition chucks can be supplied for any substrate size and can be adapted to your requirements. We also provide precise and cost efficient shadow masks made of various materials like metal, silicon, glass or ceramic.



Benefits of the Shadow Mask Aligner

- Precise and reproducible PVD layer structuring
- Vibration-resistant chuck for PVD
- Easy, damage free wafer clamping mechanism
- Simple handling during alignment due to vacuum clamping
- Ideal for different wafer sizes
- Customized chuck
- No installation
- Low running costs

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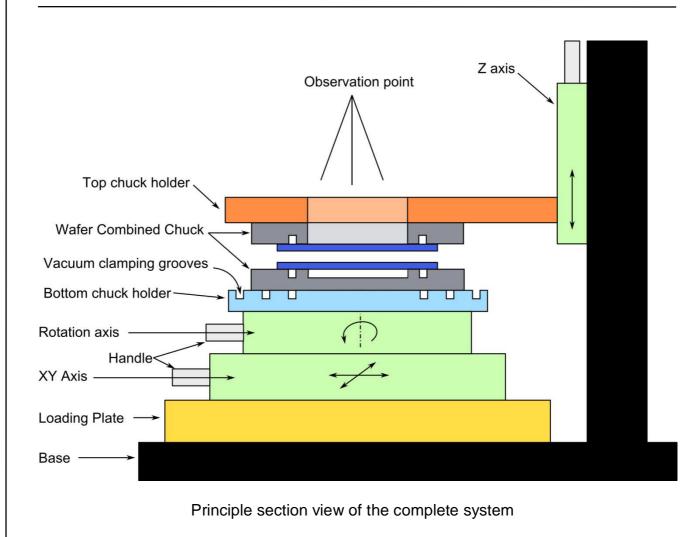
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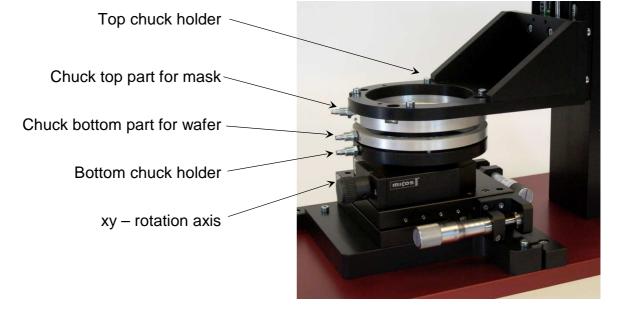
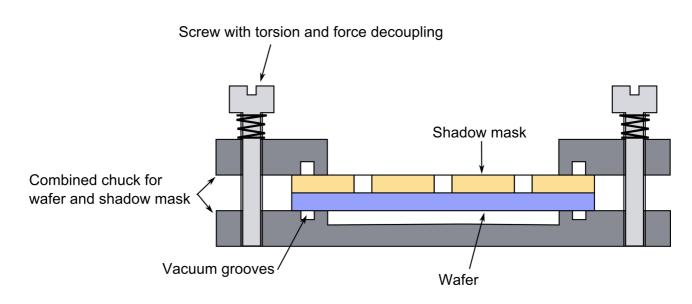


Image of a 100 mm system with a chuck ready for alignment

Details: Chuck



Principle section view of the chuck with clamped wafer and mask. With the chuck any wafer and mask thickness can be clamped. The chuck exists for 100 / 150 and 200mm standard wafer size. Special sizes can be supplied.



Bottom (left) and top part of the chuck with vacuum connector. For the bottom part we also fabricate a version with opening.



Details: Vacuum unit



Bottom unit slid out to load bottom chuck with wafer. Top chuck ready to insert mask (mask not loaded in picture).



Pneumatic board for individual regulation of wafer, mask and chuck clamping during alignment.

Technical Specifications

Product Code	SMA
Wafer and mask sizes	
Diameter	100, 150 or 200 mm depending on equipment configuration
Thickness	independent
Stage characteristics	
Range in X and Y	Scale step 10 µm - sensitivity 2 µm
Range in Z	Scale step 10 µm - sensitivity 2 µm
Rotation	360° endless
Tilt	Factory calibrated and manual adjustment by technician
Alignment precision	After sputtering
Linear alignment	Typically 6 μm ; Max 10 μm
Rotation alignment	0.001 to 0.009 Deg
Chuck	
Wafer sizes	100 mm or 150 mm or 200 mm
Chuck material	Aluminium with or without anodizing
Chuck thickness	20 mm depending on wafer and mask thickness
Shadow mask	Customized shadow masks can be provided
Material	Silicon, quartz, glass, metal, ceramic
Dimension (mm)	
Footprint (WxD)	500 x 250 mm ²
Installation	
Need of	Microscope for visual control during alignment Vacuum

Note: System can be customized, please sent us your special requirements!

Contact Idonus Sarl Rouges-Terres 61 2068 Hauterive / NE Switzerland Phone: +41 32 724 44 40 Fax: +41 32 724 44 42 Email: info@idonus.com Web: www.idonus.com

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